MOSFETs Silicon P-Channel MOS (U-MOSVI)

TJ10S04M3L

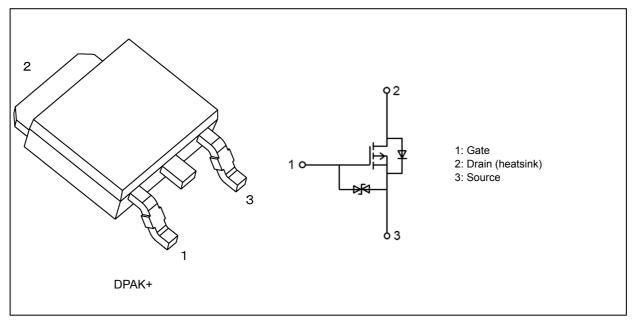
1. Applications

- Automotive
- Motor Drivers
- DC-DC Converters
- Switching Voltage Regulators

2. Features

- (1) AEC-Q101 qualified
- (2) Low drain-source on-resistance: $R_{DS(ON)} = 33.8 \text{ m}\Omega$ (typ.) (V_{GS} = -10 V)
- (3) Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -40 \ V)$
- (4) Enhancement mode: V_{th} = -2.0 to -3.0 V (V_{DS} = -10 V, I_D = -1 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics				Rating	Unit
Drain-source voltage			V _{DSS}	-40	V
Gate-source voltage			V _{GSS}	-20/+10	1
Drain current (DC)		(Note 1)	Ι _D	-10	Α
Drain current (pulsed)		(Note 1)	I _{DP}	-20	
Power dissipation	(T _c = 25°C)		PD	27	W
Single-pulse avalanche energy		(Note 2)	E _{AS}	23	mJ
Avalanche current			I _{AR}	-10	Α
Channel temperature		(Note 3)	T _{ch}	175	°C
Storage temperature		(Note 3)	T _{stg}	-55 to 175]

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	5.4	°C/W

Note 1: Ensure that the channel temperature does not exceed 175°C.

Note 2: V_{DD} = -25 V, T_{ch} = 25°C (initial), L = 243 μ H, R_G = 25 Ω , I_{AR} = -10 A

Note 3: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

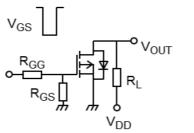
6.1. Static Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V _{GS} = -16/+10 V, V _{DS} = 0 V	_	_	±10	μA
Drain cut-off current	I _{DSS}	$V_{\rm DS}$ = -40 V, $V_{\rm GS}$ = 0 V	_	_	-10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = -10 mA, V _{GS} = 0 V	-40	_	—	V
Drain-source breakdown voltage (Note 4)	V _{(BR)DSX}	I _D = -10 mA, V _{GS} = 10 V	-30	—	_	
Gate threshold voltage	V _{th}	V _{DS} = -10 V, I _D = -1 mA	-2.0	_	-3.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = -6 V, I _D = -5 A	_	42	62	mΩ
		V _{GS} = -10 V, I _D = -5 A		33.8	44	

Note 4: If a forward bias is applied between gate and source, this device enters V_{(BR)DSX} mode. Note that the drainsource breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	_	930	_	pF
Reverse transfer capacitance	C _{rss}		_	90	—	
Output capacitance	C _{oss}			140	_	
Switching time (rise time)	t _r	See Figure 6.2.1.	_	7	_	ns
Switching time (turn-on time)	t _{on}		_	15	—	
Switching time (fall time)	t _f			40	_	
Switching time (turn-off time)	t _{off}		_	145	_	



$$\begin{split} V_{DD} &\approx -20 \text{ V} \\ V_{GS} &= 0 \text{ V}/-10 \text{ V} \\ I_D &= -5 \text{ A} \\ R_L &= 4 \Omega \\ R_{GG} &= R_{GS} &= 4.7 \Omega \\ Duty &\leq 1 \ \%, \ t_w &= 10 \ \mu s \end{split}$$

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD}\approx$ -32 V, V_{GS} = -10 V, I_{D} = -10 A	_	19	—	nC
Gate-source charge	Q _{gs}		_	13.5	_	
Gate-drain charge	Q _{gd}		_	5.5	_	

6.4. Source-Drain Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (DC)	(Note 5)	I _{DR}	—	_	_	-10	А
Reverse drain current (pulsed)	(Note 5)	I _{DRP}	—	_	_	-20	
Diode forward voltage		V _{DSF}	I _{DR} = -10 A, V _{GS} = 0 V	_		1.2	V
Reverse recovery time		t _{rr}	I _{DR} = -10 A, V _{GS} = 0 V	_	28	_	ns
Reverse recovery charge		Q _{rr}	dl _{DR} /dt = 50 A/µs		11	_	nC

Note 5: Ensure that the channel temperature does not exceed 175°C.

7. Marking (Note)

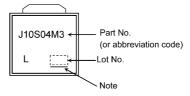
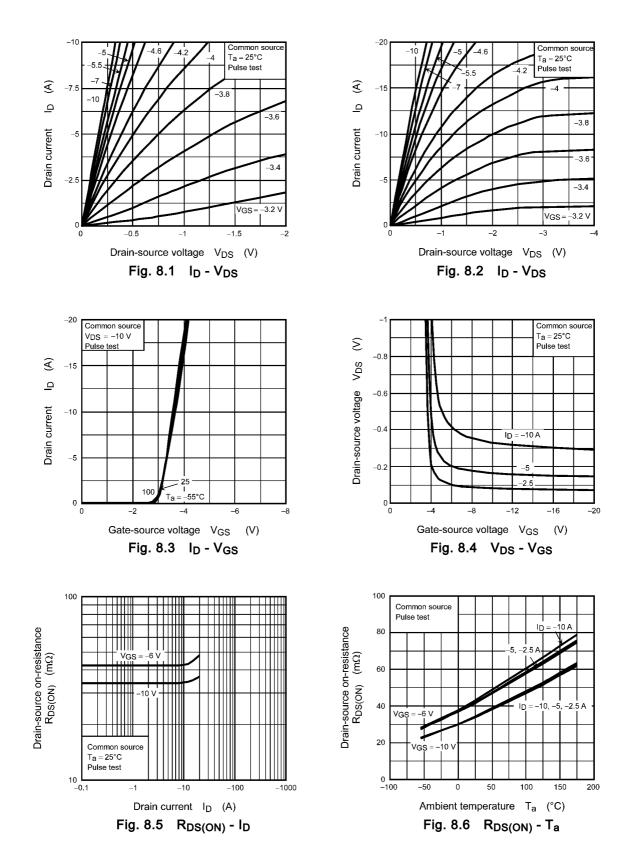


Fig. 7.1 Marking

 Note: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]
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8. Characteristics Curves (Note)



S

Gate threshold voltage

-2

0 _100

-50

0

50

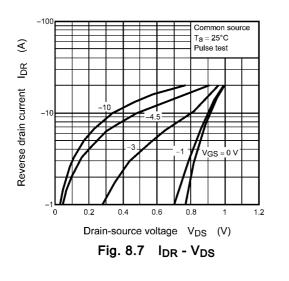
Ambient temperature Ta (°C)

Fig. 8.9 V_{th} - T_a

100

150

200



Common source $V_{DS} = -10 V$ $I_{D} = -1 mA$

Pulse test

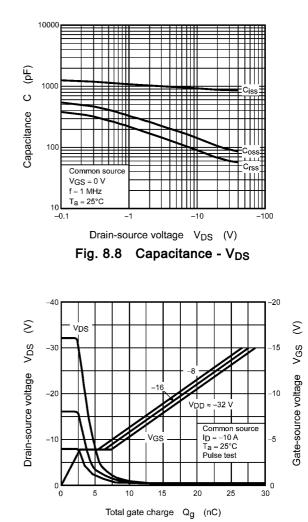
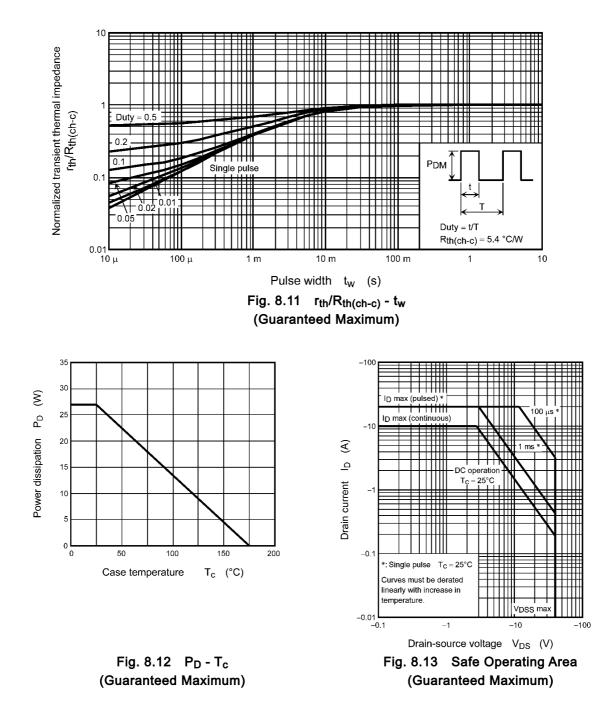


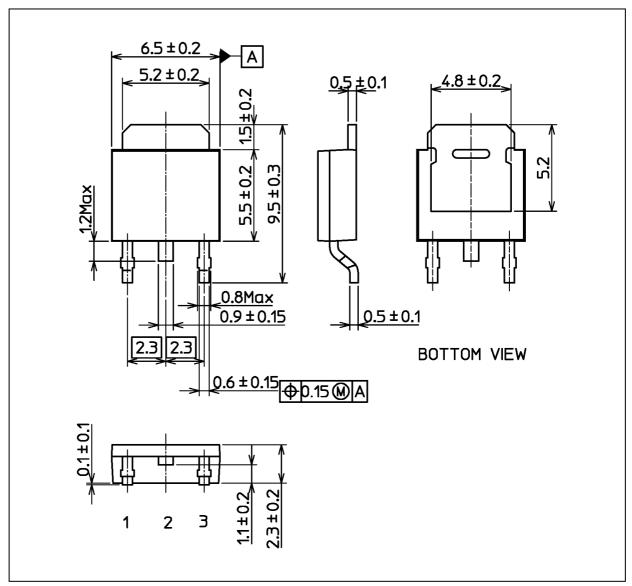
Fig. 8.10 Dynamic Input/Output Characteristics



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.36 g (typ.)

	Package Name(s)
TOSHIBA: 2-7M1A	
Nickname: DPAK+	

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